# NSN 5962-01-389-6021

Memory Microcircuit - Page 1 of 1



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## Maximum Power Dissipation Rating: 1.0 watts

**Operating Tempurature Range:** 

-55.0/+125.0 degrees celsius

## Storage Tempurature Range:

-65.0/+150.0 degrees celsius

## **End Application:**

Instrument landing system 2&3

#### **Features Provided:**

Monolithic and programmable and ultraviolet erasable

### Inclosure Configuration:

Dual-in-line

**Output Logic Form:** 

Complementary-metal oxide-semiconductor logic

#### **Product Name:**

Microcircuit, memory, digital, cmos, uv erasable programmable logic device, monolithic silicon

#### Voltage Rating And Type Per Characteristic:

-2.0 volts power source and 7.0 volts power source

## Memory Device Type:

Pal

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

#### **Terminal Type And Quantity:**

24 printed circuit

#### Shelf Life:

N/a

#### Unit Of Measure:

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#### Demilitarization:

Yes - demil/mli

#### Fiig:

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